NSN 5961-01-037-4990

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Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-037-4990 **Inclosure Material:** Metal **Overall Length:** 1.252 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** -80.0 collector to base voltage/static/emitter open and -80.0 collector to emitter voltage/static/base open and -7.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** -4.00 amperes source cutoff current **Power Rating Per Characteristic:** 25.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius ambient air **Special Features:** Item provided w/2 lugs attached to to-66 pins.; junction pattern arrangement: pnp **Terminal Type And Quantity:** 2 tab, solder lug and 1 case Shelf Life: N/a **Unit Of Measure: Demilitarization:** Yes - demil/mli